Electronic Circuits

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FET Amplifiers

FETs provide:

- Excellent voltage gain High input impedance Low-power consumption Good frequency range

FET Small-Signal Model

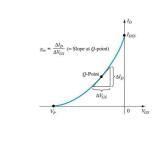
Transconductance

The relationship of a change in ${\rm I}_{\rm D}$ to the corresponding change in ${\rm V}_{\rm GS}$ is called transconductance

Transconductance is denoted g_m and given by:

$$g_m = \frac{\Delta I_D}{\Delta V_{max}}$$

Graphical Determination of g_m



Mathematical Definitions of g_m

$$\begin{aligned} \mathbf{g}_{m} &= \frac{\Delta I_{D}}{\Delta V_{GS}} \\ \mathbf{g}_{m} &= \frac{2I_{DSS}}{|V_{P}|} \left[1 - \frac{V_{GS}}{V_{P}}\right] \\ \end{aligned}$$
 Where $V_{GS} = 0V$ $\mathbf{g}_{m0} = \frac{2I_{DSS}}{|V_{P}|} \\ \mathbf{g}_{m} &= \mathbf{g}_{m0} \left[1 - \frac{V_{GS}}{V_{CS}}\right] \end{aligned}$

$$V_{P} = \sqrt{I_{DSS}}$$

$$g_{m} = g_{m0} \left(1 - \frac{V_{GS}}{V_{P}}\right) = g_{m0} \sqrt{\frac{I_{D}}{I_{DSS}}}$$

FET Impedance

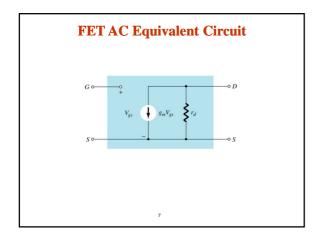
$$Z_i = \infty \Omega$$

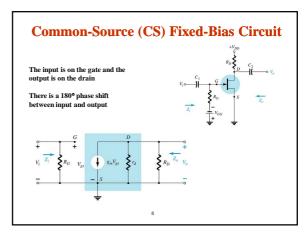
$$Z_o = r_d = \frac{1}{y_{os}}$$

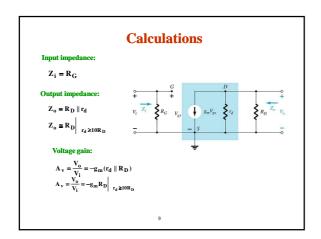
$$r_d = \frac{\Delta V_{DS}}{\Delta I_D} \Big|_{V_{GS} = constant}$$

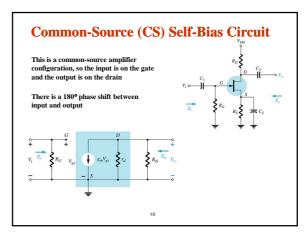
admittance parameter listed on FET specification sheets.

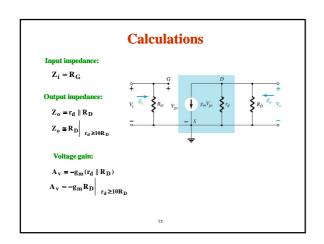
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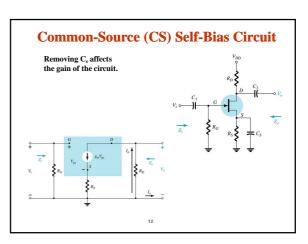


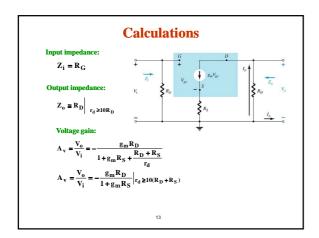


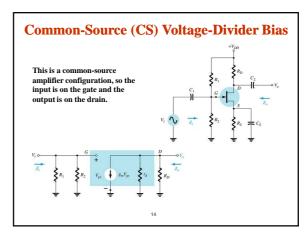


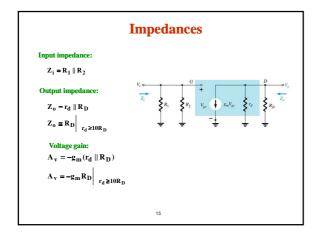


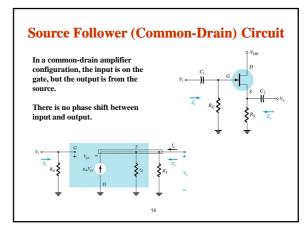


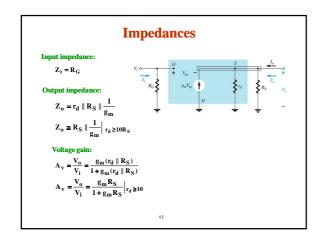


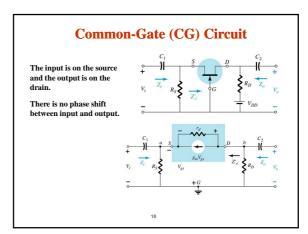


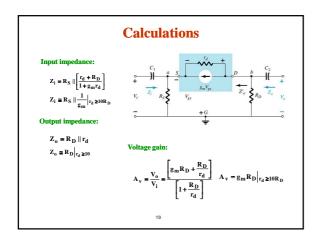


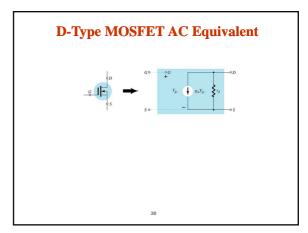


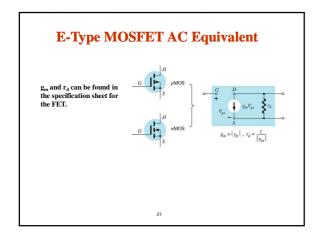


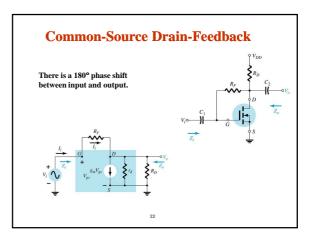


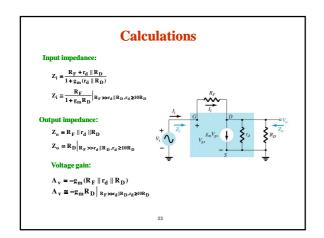


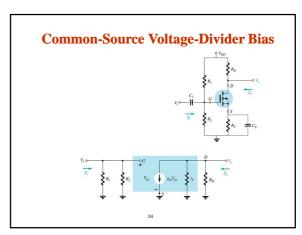


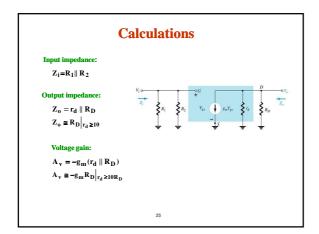


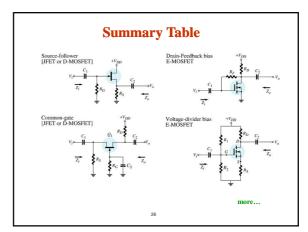


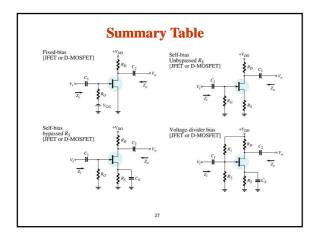


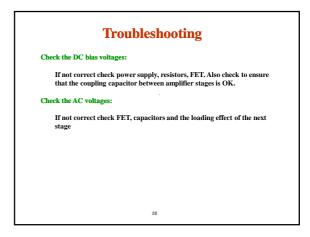












Practical Applications Three-Channel Audio Mixer Silent Switching Phase Shift Networks Motion Detection System